

Preliminary

TSM4835

30V P-Channel MOSFET



SOP-8



Pin Definition:

- 1. Source
- 2. Source
- 3. Source
- 4. Gate
- 5, 6, 7, 8. Drain

PRODUCT SUMMARY

V _{DS} (V)	$R_{DS(on)}(m\Omega)$	I _D (A)	
-30	18 @ V _{GS} = -10V	-9.6	
	30 @ V _{GS} = -4.5V	-7.5	

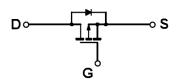
Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

- Load Switches
- Desktop PCs
- Notebook PCs

Block Diagram



P-Channel MOSFET

Ordering Information

Part No.	Package	Packing
TSM4835CS RL	SOP-8	2.5Kpcs / 13" Ree

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	-30	V
Gate-Source Voltage		V _{GS} ±25		V
Continuous Drain Current	ntinuous Drain Current		-9.6	Α
Pulsed Drain Current		I _{DM}	-50	Α
Continuous Source Current (Diode C	onduction) ^{a,b}	I _S	-2.1	Α
Maximum Power Dissipation	Ta = 25°C	- P _D	2.5	W
	Ta = 75°C		1.6	
Operating Junction Temperature	•	TJ	+150	°C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	- 55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit			
Junction to Foot (Drain) Thermal Resistance	R⊖ _{JF}	18	°C/W			
Junction to Ambient Thermal Resistance (PCB mounted)	RΘ _{JA}	39	°C/W			

Notes:

- a. Pulse width limited by the Maximum junction temperature
- b. Surface Mounted on FR4 Board, t ≤ 10 sec.

1/1 Version: Preliminary



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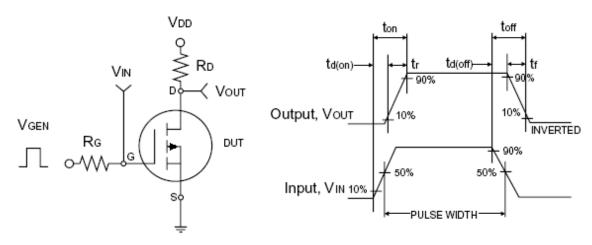


Electrical Specifications (Ta = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static	Static					
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = -250uA$	BV _{DSS}	-30	I		V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	$V_{GS(TH)}$	-1	I	-3	V
Gate Body Leakage	$V_{GS} = \pm 25V, V_{DS} = 0V$	I_{GSS}		1	±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -30V, V_{GS} = 0V$	I _{DSS}			-1.0	μA
On-State Drain Current ^a	V _{DS} ≤ -5V, V _{GS} = -10V	I _{D(ON)}	-50			Α
Drain-Source On-State Resistance	$V_{GS} = -10V, I_D = -9.6A$	0		14	18	mΩ
Drain-Source On-State Resistance	$V_{GS} = -4.5V, I_D = -7.5A$	$R_{DS(ON)}$		23	30	
Forward Transconductance ^a	$V_{DS} = -15V, I_{D} = -9.6A$	g _{fs}		30		S
Diode Forward Voltage	I _S = -2.1A, V _{GS} = 0V	V_{SD}		-0.8	-1.2	V
Dynamic ^b						
Total Gate Charge	$V_{DS} = -15V, I_{D} = -9.6A,$	Q_g		25	37	
Gate-Source Charge	$V_{DS} = -15V, I_D = -9.0A,$ $V_{GS} = -5V$	Q_gs		6.5		nC
Gate-Drain Charge	V _{GS} = -5 V	Q_{gd}		12.5		
Input Capacitance	\/ - 15\/ \/ - 0\/	C_{iss}		2089	2347	
Output Capacitance	$V_{DS} = -15V, V_{GS} = 0V,$ f = 1.0MHz	C _{oss}		597		pF
Reverse Transfer Capacitance	1 - 1.000112	C_{rss}		495	624	
Switching ^c						
Turn-On Delay Time	V - 45V D - 450	t _{d(on)}		15	25	
Turn-On Rise Time	$V_{DD} = -15V, R_{L} = 15\Omega,$ $I_{D} = -1A, V_{GEN} = -10V,$	t _r		13	20	nS
Turn-Off Delay Time		$t_{d(off)}$		60	100	113
Turn-Off Fall Time	$R_G = 6\Omega$	t _f		45	70	

Notes:

- a. pulse test: PW $\leq 300 \mu S$, duty cycle $\leq 2\%$ b. For DESIGN AID ONLY, not subject to production testing.
- b. Switching time is essentially independent of operating temperature.



Switching Test Circuit

Switchin Waveforms

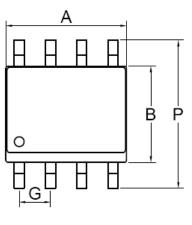


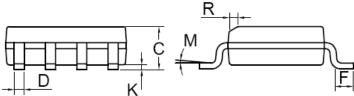
TSM4835





SOP-8 Mechanical Drawing





SOP-8 DIMENSION					
DIM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX.	
Α	4.80	5.00	0.189	0.196	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.05	BSC	
K	0.10	0.25	0.004	0.009	
М	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	



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